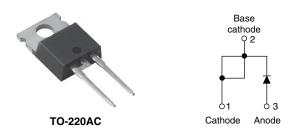


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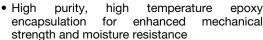
## Schottky Rectifier, 10 A

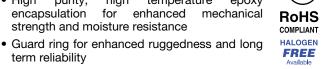


PRODUCT SUMMARY					
Package	TO-220AC				
I <sub>F(AV)</sub>	10 A				
$V_{R}$	35 V, 45 V				
V <sub>F</sub> at I <sub>F</sub>	0.57 V				
I <sub>RM</sub> max.	15 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Single die				
E <sub>AS</sub>	8 mJ				

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- High frequency operation
- · Low forward voltage drop





- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### **DESCRIPTION**

term reliability

This Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	10	^			
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C	20	Α			
V <sub>RRM</sub>		35/45	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	Α			
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V			
T <sub>J</sub>	Range	- 65 to 150	°C			

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBR1035PbF	VS-MBR1035-N3	VS-MBR1045PbF	VS-MBR1045-N3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	35	35	45	45	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	33	35	43	43	V			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 135 °C, rated V <sub>R</sub>		10	А	
Peak repetitive forward current	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20	kHz, $T_C = 135$ °C	20		
Non-repetitive peak surge current	I <sub>ESM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	А	
, ,	T GIVI	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150		
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 4  \text{mH}$		8	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by $T_J$ maximum $V_A = 1.5$ x $V_R$ typical		2	Α	



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
		20 A	T <sub>J</sub> = 25 °C	0.84		
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	T 405.00	0.57	V	
		20 A	T <sub>J</sub> = 125 °C	0.72		
NAi	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	mA	
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	hated DC voltage	15		
Threshold voltage	V <sub>F(TO)</sub>	$T_{.1} = T_{.1}$ maximum		0.354	V	
Forward slope resistance	r <sub>t</sub>	ıj = ıj maximum		17.6	mΩ	
Maximum junction capacitance	C <sub>T</sub>	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		600	pF	
Typical series inductance	L <sub>S</sub>	Measured from top of term	8.0	nΗ		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs		

#### Note

 $<sup>^{(1)}</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction temperature range	$T_J$		- 65 to 150	°C		
Maximum storage temperature range	T <sub>Stg</sub>		- 65 to 175	Ò		
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.0	°C/W		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased (only for TO-220)	0.50	]		
Approximate weight			2	g		
Approximate weight			0.07	oz.		
Mounting torque minimum			6 (5)	kgf ⋅ cm		
maximum			12 (10)	(lbf $\cdot$ in)		
Marking device		Constitute TO 200AC	MBR1035			
ivial Killy device		Case style TO-220AC	MBR1045			

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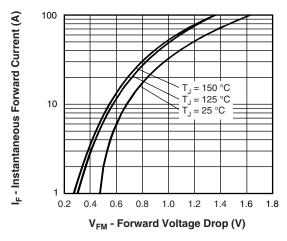


Fig. 1 - Maximum Forward Voltage Drop Characteristics

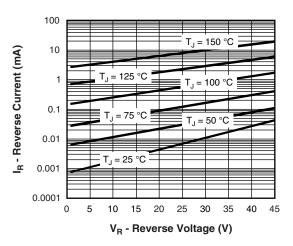


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

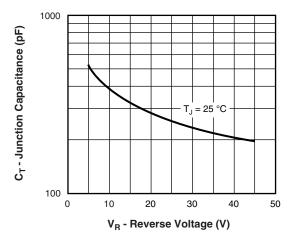


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

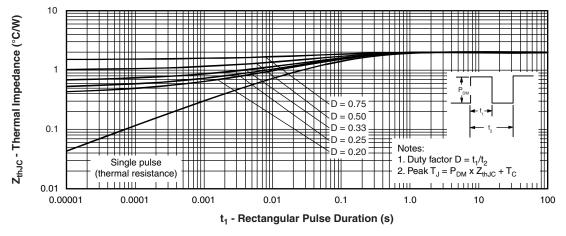


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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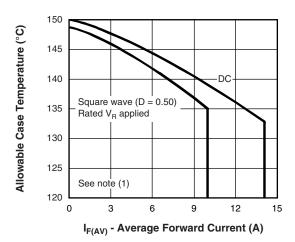


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

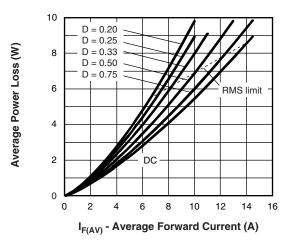


Fig. 6 - Forward Power Loss Characteristics

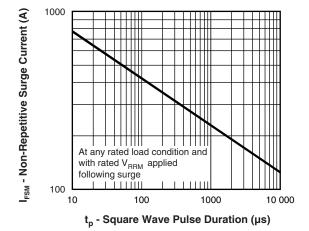


Fig. 7 - Maximum Non-Repetitive Surge Current

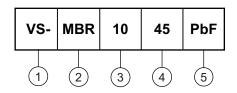
#### Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

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#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

2 - Schottky MBR series

Currrent rating (10 = 10 A)

- Voltage ratings - 35 = 35 V 45 = 45 V

5 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-MBR1035PbF	50	1000	Antistatic plastic tube			
VS-MBR1035-N3	50	1000	Antistatic plastic tube			
VS-MBR1045PbF	50	1000	Antistatic plastic tube			
VS-MBR1045-N3	50	1000	Antistatic plastic tube			

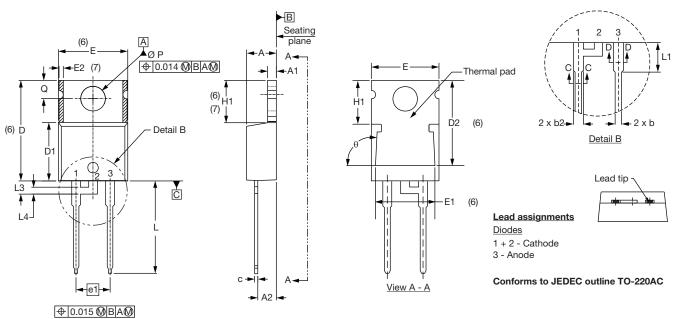
LINKS TO RELATED DOCUMENTS					
Dimensions		www.vishay.com/doc?95221			
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224			
	TO-220AC -N3	www.vishay.com/doc?95068			
SPICE model		www.vishay.com/doc?95293			



### Vishay Semiconductors

### **TO-220AC**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		INCHES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	RS INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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